

# SANYO Semiconductors DATA SHEET

# CPH6071—Video Output Driver, High-Frequency Amplifier Applications

## **Features**

- Composite type with NPN transistor and PNP transistor contained in the conventional CPH package improving the mounting efficiency greatly.
- The CPH6071 is formed with two chips, being equivalent to the 2SC4504 and the other the 2SA1724, placed in one package.

# **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
[TR1(NPN Tr)]	<u> </u>	,		
Collector-to-Base Voltage	VCBO		30	V
Collector-to-Emitter Voltage	VCEO		20	V
Emitter-to-Base Voltage	VEBO		3	V
Collector Current	IC		300	mA
Collector Current (Pulse)	ICP		600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm²X0.8mm)	0.9	W
[TR2(PNP Tr)]	•			
Collector-to-Base Voltage	VCBO		-30	V
Collector-to-Emitter Voltage	VCEO		-20	V
Emitter-to-Base Voltage	VEBO		-3	V
Collector Current	IC		-300	mA
Collector Current (Pulse)	ICP		-600	mA
Collector Dissipation	PC	Mounted on a ceramic board (600mm²x0.8mm)	0.9	W
[Common Ratings]				
Total Dissipation	PT	Mounted on a ceramic board (600mm²X0.8mm)	1.1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Marking: GH

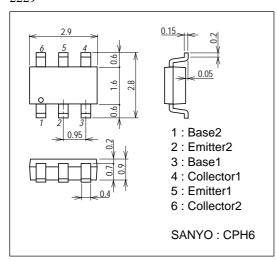
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# Electrical Characteristics at Ta=25°C

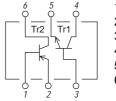
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
[TR1(NPN Tr)]					,	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =20V, I <sub>E</sub> =0			0.1	μΑ
Emitter Cutoff Current	IEBO	VEB=2V, IC=0			5.0	μΑ
DC Current Gain	hFE(1)	V <sub>CE</sub> =5V, I <sub>C</sub> =50mA	100		200	
	hFE(2)	VCE=5V, IC=300mA	20			
Gain-Bandwidth Product	fŢ	V <sub>CE</sub> =5V, I <sub>C</sub> =50mA		2.2		GHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		2.9		pF
Reverse Transfer Capacitance	Cre	V <sub>CB</sub> =10V, f=1MHz		2.6		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA		0.15	0.5	V
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=100mA, IB=10mA		0.9	1.2	V
[TR2(PNP Tr)]						
Collector Cutoff Current	ІСВО	V <sub>CB</sub> =-20V, I <sub>E</sub> =0			-0.1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =-2V, I <sub>C</sub> =0			-1.0	μΑ
DC Current Gain	hFE(1)	VCE=-5V, IC=-50mA	15		100	
	hFE(2)	V <sub>CE</sub> =-5V, I <sub>C</sub> =-300mA	5			
Gain-Bandwidth Product	fŢ	V <sub>CE</sub> =-5V, I <sub>C</sub> =-100mA		1.5		GHz
Output Capacitance	Cob	VCB=-10V, f=1MHz		4.9		pF
Reverse Transfer Capacitance	Cre	V <sub>CB</sub> =-10V, f=1MHz		4.4		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> =-100mA, I <sub>B</sub> =-10mA		-0.4	-1.0	V
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=-100mA, IB=-10mA		-0.9	-1.2	V

## **Package Dimensions**

unit : mm 2229



#### **Electrcal Connection**

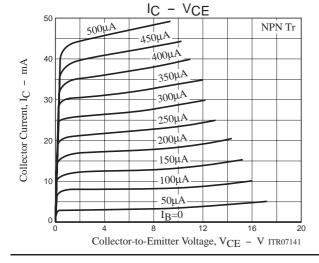


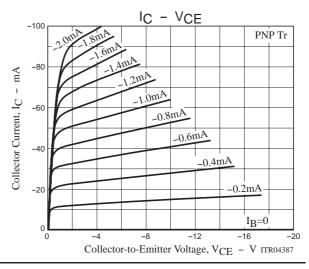
1 : Base2 2 : Emitter2

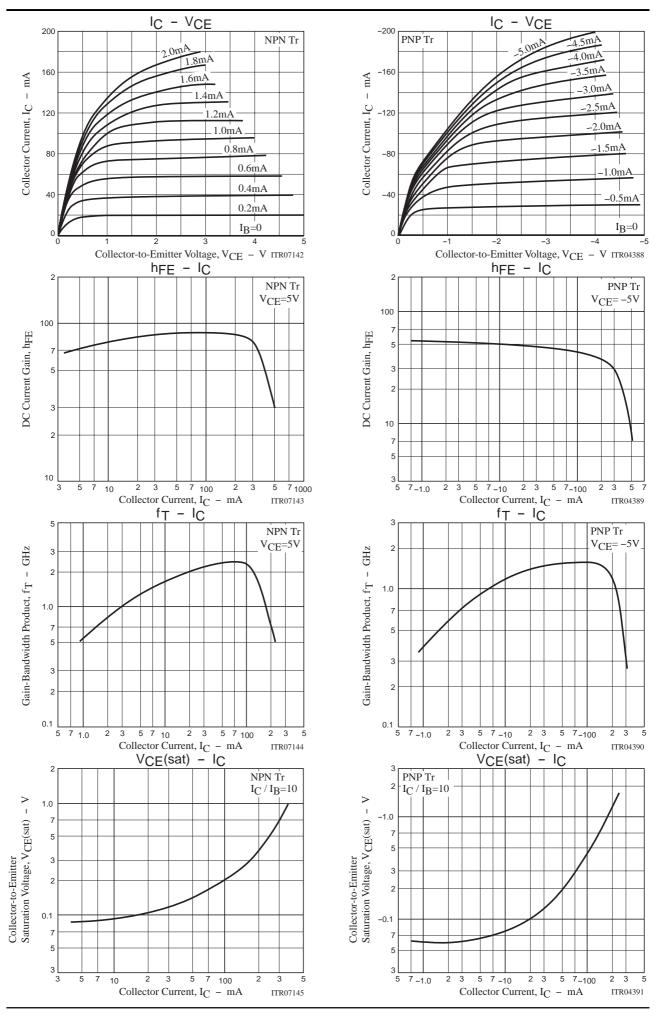
3 : Base1 4 : Collector1

5 : Emitter1 6 : Collector2

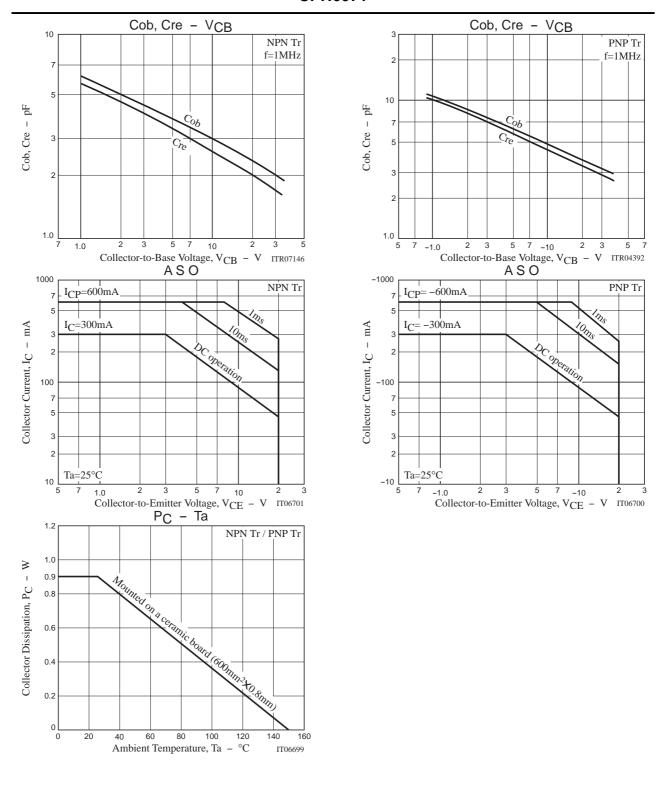
Top view







# **CPH6071**



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